General Description

The LTA180 series of current sense amplifiers (also called current shunt monitors) are designed for cost-optimized applications, that sense voltage drops across current-sense resistors at common-mode voltages from -0.2 V to +26 V, independent of the supply voltage. The LTA180 series integrate a matched resistor gain network in four fixed-gain device options: 20 V/V, 50 V/V, 100 V/V, or 200 V/V. This matched gain resistor network minimizes gain error and reduces the temperature drift.

The LTA180 series operate from a single +2.7-V to +5.5-V power supply, drawing a maximum of $110\mu A$ of supply current. The device is specified from -40°C to +125°C, and offered in SOT23-5L packages.

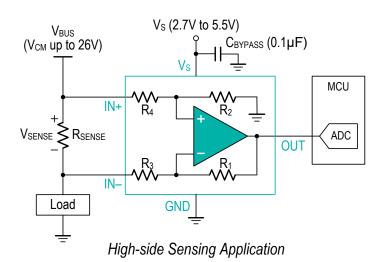
Features and Benefits

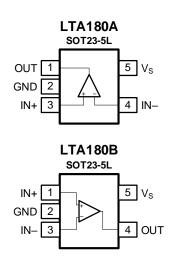
- Wide common-mode range: -0.2 V to 26 V
- Offset voltage
 - \pm 150 μV Maximum at V_{CM} = 0 V
 - \pm 500 μ V Maximum at V_{CM} = 12 V
- Accuracy
 - Maximum ±1% Gain Error
 - Maximum 1 μV/°C Offset Drift
- Gains Options:
 - 20V/V (LTA180A1, LTA180B1)
 - 50V/V (LTA180A2, LTA180B2)
 - 100V/V (LTA180A3, LTA180B3)
- 200V/V (LTA180A4, LTA180B4)
- Output slew rate: 1.3 V/μs
- Quiescent Current: Maximum 230μA
- Package: S0T23-5L

Applications

- Motor Control
- Battery Monitor, BMS
- Power Management
- Lighting Control
- Over-Current Detection
- Solar Inverters

Block Diagram and Pin Configuration (Top View)







Low- and High-Side Voltage Output, Current Sense Amplifiers

Pin Description

Symbol	Description						
IN-	Current-sense amplifier negative input. For high-side applications, connect to load side of sense resistor. For low-side applications, connect to ground side of sense resistor.						
IN+	Current-sense amplifier positive input. For high-side applications, connect to bus-voltage (V _{BUS}) side of sense resistor. For low-side applications, connect to load side of sense resistor. Output voltage. The voltage range extends to within millivolt of each supply rail. Positive power supply. Typically, the voltage is from 2.7 V to 5.5 V. A bypass capacitor of 0.1µF as close to the part as possible should be used between power supply pin and ground pin.						
OUT							
V _S							
GND	Negative power supply.						

Ordering Information

Orderable Type Number	Gain (V/V)	Package Name	Package Quantity	Eco Class ⁽¹⁾	Marking Code
LTA180A1XT5/R6	20	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8A1
LTA180A2XT5/R6	50	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8A2
LTA180A3XT5/R6	100	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8A3
LTA180A4XT5/R6	200	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8A4
LTA180B1XT5/R6	20	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8B1
LTA180B2XT5/R6	50	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8B2
LTA180B3XT5/R6	100	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8B3
LTA180B4XT5/R6	200	S0T23-5L	3 000	Green (RoHS & no Sb/Br)	8B4

⁽¹⁾ Eco Class - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & Halogen Free).

Limiting Value

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Absolute Maximum Rating				
Supply Voltage, V _S to GND	+10 V				
Analog Inputs (IN+, IN-), Differential $(V_{IN+} - V_{IN-})$	-26 V to +26 V				
Analog Inputs (IN+, IN-), Common-Mode	(GND – 0.3V) to +26 V				
Input Current Into All Pins	5 mA				
Output	(GND – 0.3V) to (V _s + 0.3V)				
Maximum output current, I _{OUT}	8 mA				
Storage Temperature Range, T _{stg}	-65 °C to +150 °C				
Junction Temperature, T _J	150 ℃				
Lead Temperature Range (Soldering 10 sec)	260 ℃				



⁽²⁾ Please contact to your Linearin representative for the latest availability information and product content details.

Low- and High-Side Voltage Output, Current Sense Amplifiers

ESD Rating

Parameter	Item	Value	Unit
	Human body model (HBM), per MIL-STD-883J / Method 3015.9	\pm 4 000	_
Electrostatic Discharge Voltage	Charged device model (CDM), per ESDA/JEDEC JS-002-2014	\pm 2 000	٧
	Machine model (MM), per JESD22-A115C	±400	•

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



Electrical Characteristics

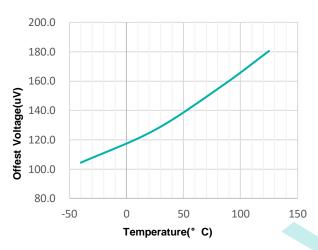
 $T_A = +25\,^{\circ}\text{C}$, $V_S = +5.0V$, $V_{IN+} = 12V$, and $V_{SENSE} = V_{IN+} - V_{IN-}$, unless otherwise noted. Boldface limits apply over the specified temperature range, $T_A = -40$ to $+125\,^{\circ}\text{C}$.

V _{os} C	RACTERISTICS Offset voltage Offset voltage drift	Referred-to-input Referred-to-input, V _{IN+} = 0 V		±100	± 500		
		Referred-to-input, V _{IN+} = 0 V		±100	+ 500		
					7 200	\/	
V _{os} TC C	Offset voltage drift		±25	±150	— μV		
		Referred-to-input, over Temperature		0.4	1	μV/°C	
l _B lı	nput bias current	$V_{SENSE} = 0 \text{ mV}, V_{IN+} = 0 \text{ V}$		0.05		– μΑ	
'B ''	iiput bias current	V _{SENSE} = 0 mV		40		μΑ	
l _{os} lı	nput offset current	V _{SENSE} = 0 mV		± 0.05		μΑ	
	Common-mode input voltage range	Referred-to-input	-0.2		26	٧	
	Common-mode ejection ratio	$V_{IN+} = 0 \text{ V to } +26 \text{ V,}$ $V_{SENSE} = 10 \text{ mV,}$ $T_A = -40 \text{ to } +125^{\circ}\text{C}$	100		dB		
OUTPUT CH	<i>IARACTERISTICS</i>						
		LTA180A1, LTA180B1		20		_	
G G	Sain					— V/V	
0	Jaili						
E _G G	Gain error	$V_{OUT} = 0.5 V$ to $V_S - 0.5 V$		± 0.1	±1	%	
E _G TC	Sain error drift	over Temperature		1.5	15	ppm/°C	
	Nonlinearity Error	$V_{OUT} = 0.5 \text{V to } V_S - 0.5 \text{ V}$		± 0.01		%	
	Maximum Capacitive Load	No sustained oscillation		1		nF	
V _{OH} S	Swing to V _S rail	$R_L = 10k\Omega$ to GND,		V _S -30		– mV	
V_{0L} S	Swing to GND	T _A = -40 to +125°C		V _{GND} +2			
DYNAMIC P	PERFORMANCE						
		LTA180A1 and LTA180B1, C _L = 10pF		160		_	
BW E	Bandwidth					_ kHz	
						_	
	Slew rate			1.5		V/µs	
	FORMANCE						
	oltage noise density	Referred-to-input		30		nV/√Hz	
POWER SUI							
	Operating supply voltage		+2.7		+6	V	
	Power supply rejection ratio	Referred-to-input, $V_S = +2.7V$ to $+5.5V$, $V_{SENSE} = 10 \text{ mV}$		±4	±20	μV/V	
	Quioscopt current	V _{SENSE} = 10 mV		180	250		
I _Q G	Quiescent current	over Temperature			290	— μΑ	
	CHARACTERISTICS						
	Operating emperature		-40		+125	°C	
	Package Thermal Resistance	S0T23-5L		190		°C/W	

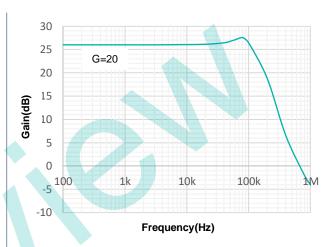


Typical Performance Characteristics

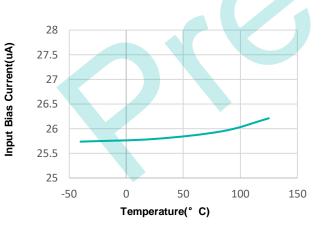
At T_A =+25°C, V_S =+5.0V, and V_{IN+} = 12V, unless otherwise noted.



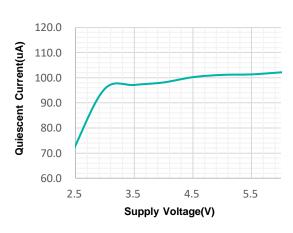
Offset Voltage vs. Temperature



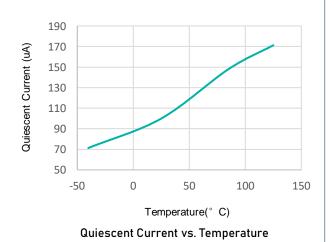
Gain vs. Frequency



Input Bias Current vs. Temperature



Quiescent Current vs. Supply Voltage



FN2308-10.3 — Data Shee!

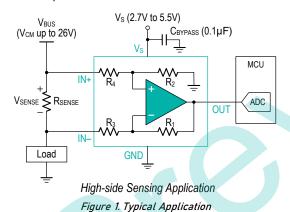
Low- and High-Side Voltage Output, Current Sense Amplifiers

Application Notes

BASIC CONNECTIONS

Figure 1 shows the basic connections for the LTA180 series. The input pins, IN+ and IN-, should be connected as closely as possible to the shunt resistor to minimize any resistance in series with the shunt resistance.

Power-supply bypass capacitors are required for stability. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.



POWER SUPPLY

The input circuitry of the LTA180 can accurately measure beyond its power-supply voltage, $V_{\rm S}$. For example, the $V_{\rm S}$ power supply can be 5V, whereas the load power-supply voltage can be from 2.7V to 5.5V. However, the output voltage range of the OUT terminal is limited by the voltages on the power-supply pin. Note also that the LTA180 can withstand the full -0.2V to +26V range in the input pins, regardless of whether the device has power applied or not.

PRECISE LOW-SIDE CURRENT SENSING

When used in low-side current sensing applications, the offset voltage of the LTA180 series is within $\pm 150 \mu V$. The low offset performance of the LT180 has several benefits. First, the low offset allows the device to be used in applications that must measure current over a wide dynamic range. In this case, the low offset improves the accuracy when the sensed currents are on the low end of the measurement range. Another advantage of low offset is the ability to sense lower voltage drop across the sense resistor accurately, thus allowing a lower-value shunt resistor. Lower-value shunt resistors reduce power loss in the current sense circuit, and help improve the power efficiency of the end application.

The gain error of the LTA180 series is specified to be within 1% of the actual value. As the sensed voltage becomes much larger than the offset voltage, this voltage becomes the dominant source of error in the current sense measurement.

INPUT DIFFERENTIAL OVERLOAD

If the differential input voltage ($V_{\text{IN+}}$ - $V_{\text{IN-}}$) times gain exceeds the voltage swing specification, the LTA180 series drive the output as close as possible to the positive supply, and does not provide accurate measurement of the

differential input voltage. If this input overload occurs during normal circuit operation, then reduce the value of the shunt resistor or use a lower-gain version with the chosen sense resistor to avoid this mode of operation. If a differential overload occurs in a fault event, then the output of the LTA180 series return to the expected value approximately 20µs after the fault condition is removed. When the LTA180 output is driven to either the supply rail or ground, increasing the differential input voltage does not damage the device as long as the absolute maximum ratings are not violated. Following these guidelines, the LT180 output maintains polarity, and does not suffer from

phase reversal. INPUT FILTERING

An obvious and straightforward filtering location is at the device output. However, this location negates the advantage of the low output impedance of the internal buffer. The only other filtering option is at the device input pins. This location, though, does require consideration of the $\pm 30\%$ tolerance of the internal resistances. Figure 2 shows a filter placed at the inputs pins.

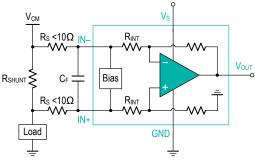


Figure 2. Filter at Input Pins

The addition of external series resistance, however, creates an additional error in the measurement so the value of these series resistors should be kept to 10Ω or less if possible to reduce impact to accuracy. The internal bias network shown in Figure 2 present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins. If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed at the shunt resistor. This error results in a voltage at the device input pins that is different than the



Low- and High-Side Voltage Output, Current Sense Amplifiers

Application Notes (continued)

voltage developed across the shunt resistor. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation. The amount of error these external filter resistor add to the measurement can be calculated using Equation 2 where the gain error factor is calculated using Equation 1.

The amount of variance in the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based both on the external series resistance value as well as the internal input resistors, R_{INT} as shown in Figure 2. The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. The equation used to calculate the expected deviation from the shunt voltage to what is seen at the device input pins is given in Equation 1:

Gain Error Factor =
$$\frac{1250 \times R_{INT}}{1250 \times R_S + 1250 \times R_{INT} + R_S \times R_{INT}}$$

where:

 R_{INT} is the internal input resistor (R3 and R4, 10k Ω), and R_{S} is the external series resistance.

The gain error that can be expected from the addition of the external series resistors can then be calculated based on Equation 2:

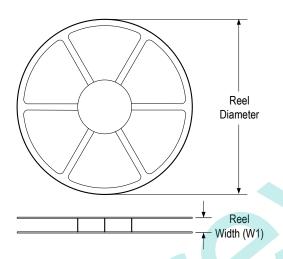
Gain Error (%) = $100 - (100 \times Gain Error Factor)$

For LTA180, a series resistance of 10Ω results in a gain error factor of 0.991. The corresponding gain error is then calculated using Equation 2, resulting in a gain error of approximately 0.89% solely because of the external 10Ω series resistors.

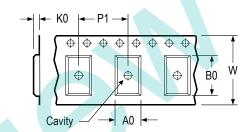


Tape and Reel Information

REEL DIMENSIONS

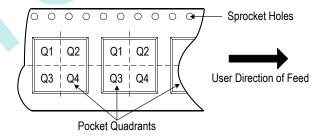


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width						
B0	Dimension designed to accommodate the component length						
K0	O Dimension designed to accommodate the component thickn						
W	Overall width of the carrier tape						
P1	Pitch between successive cavity centers						

QUADRANT ASSIGNMENTS FOR PIN 1 ORIETATION IN TAPE



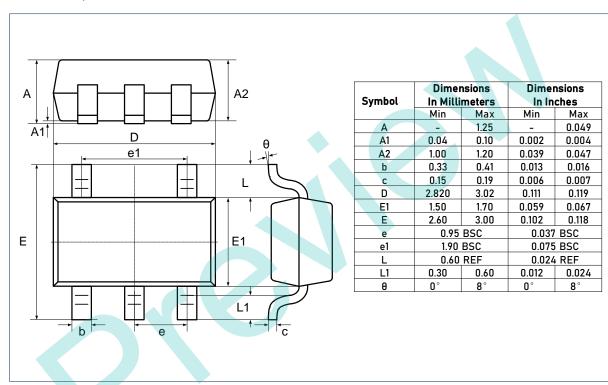
* All dimensions are nominal

Device	Package Type	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin 1 Quadrant
LTA180xxXT5/R6	S0T23	5	3 000	178	9.0	3.3	3.2	1.5	4.0	8.0	Q3

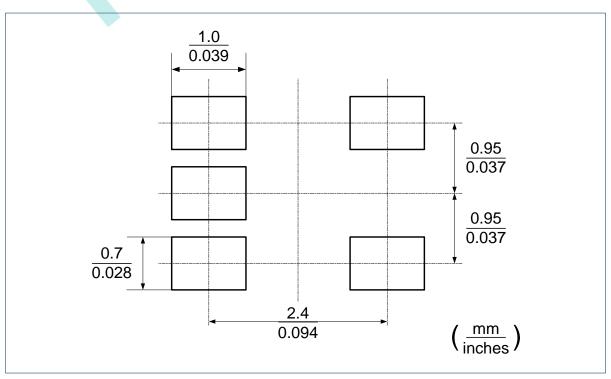


Package Outlines

DIMENSIONS, SOT23-5L



RECOMMENDED SOLDERING FOOTPRINT, SOT23-5





IMPORTANT NOTICE

Linearin is a global fabless semiconductor company specializing in advanced high-performance high-quality analog/mixed-signal IC products and sensor solutions. The company is devoted to the innovation of high performance, analog-intensive sensor front-end products and modular sensor solutions, applied in multi-market of medical & wearable devices, smart home, sensing of IoT, and intelligent industrial & smart factory (industrie 4.0). Linearin's product families include widely-used standard catalog products, solution-based application specific standard products (ASSPs) and sensor modules that help customers achieve faster time-to-market products. Go to http://www.linearin.com for a complete list of Linearin product families.

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